

L Number	Hits	Search Text	DB	Time stamp
1	6152	cathode same (etch\$2 or etching or electro\$1etch\$3 or electro\$1polish\$3)	USPAT	2003/11/25 10:35
2	3338	(cathode same (etch\$2 or etching or electro\$1etch\$3 or electro\$1polish\$3)) and semiconductor	USPAT	2003/11/25 10:35
3	2101	((cathode same (etch\$2 or etching or electro\$1etch\$3 or electro\$1polish\$3)) and semiconductor) and ((power or current or voltage) with cathode)	USPAT	2003/11/25 10:36
4	1706	((cathode same (etch\$2 or etching or electro\$1etch\$3 or electro\$1polish\$3)) and semiconductor) and ((power or current or voltage) with cathode)) and anode	USPAT	2003/11/25 10:38
5	1680	((cathode same (etch\$2 or etching or electro\$1etch\$3 or electro\$1polish\$3)) and semiconductor) and ((power or current or voltage) with cathode)) and anode) and @ay<=2001	USPAT	2003/11/25 10:38
6	594	((cathode same (etch\$2 or etching or electro\$1etch\$3 or electro\$1polish\$3)) and semiconductor) and ((power or current or voltage) with cathode)) and anode) and @ay<=2001) and (copper or Cu)	USPAT	2003/11/25 10:43
7	246	((cathode same (etch\$2 or etching or electro\$1etch\$3 or electro\$1polish\$3)) and semiconductor) and ((power or current or voltage) with cathode)) and anode) and @ay<=2001) and ((etch or etching or etched or electro\$1etch\$3) same (copper or Cu))	USPAT	2003/11/25 10:46
8	206	((cathode same (etch\$2 or etching or electro\$1etch\$3 or electro\$1polish\$3)) and semiconductor) and ((power or current or voltage) with cathode)) and anode) and @ay<=2001) and ((etch or etching or etched or electro\$1etch\$3) same (copper or Cu)) and (mask or plate or hard\$1mask)	USPAT	2003/11/25 11:32
9	12	("3959089"   "5256565"   "5567300"   "5863412"   "5993637"   "6017437"   "6056869"   "6077412"   "6171467"   "6176992"   "6299741"   "6328872").PN.	USPAT	2003/11/25 11:18
10	2	("4871416"   "5686789").PN.	USPAT	2003/11/25 11:28
11	153	((cathode same (etch\$2 or etching or electro\$1etch\$3 or electro\$1polish\$3)) and semiconductor) and ((power or current or voltage) with cathode)) and anode) and @ay<=2001) and ((etch or etching or etched or electro\$1etch\$3) same (copper or Cu)) and (mask or plate or hard\$1mask)) and @py<=2001	USPAT	2003/11/25 11:33
12	58	((cathode same (etch\$2 or etching or electro\$1etch\$3 or electro\$1polish\$3)) and semiconductor) and ((power or current or voltage) with cathode)) and anode) and @ay<=2001) and ((etch or etching or etched or electro\$1etch\$3) same (copper or Cu)) and (mask or plate or hard\$1mask)) and @py<=2001) not plasma	USPAT	2003/11/25 13:28

23	31	((cathode near4 (plurality or second or two)) and semiconductor) and anode) and (electro\$etch or electro\$etching or electro\$polish or electro\$polishing)	USPAT	2003/11/25 13:57
24	15	((cathode near4 (plurality or second or two)) and semiconductor) and anode) and (electro\$etch or electro\$etching or electro\$polish or electro\$polishing)) not ((electro\$etch or electro\$etching) and semiconductor) and @ay<=2001)	USPAT	2003/11/25 13:55
25	771	electro\$etch or electro\$etching or electro\$polish or electro\$polishing	US-PGPUB; EPO; JPO	2003/11/25 13:58
26	548	(electro\$etch or electro\$etching or electro\$polish or electro\$polishing) and @ay<=2001	US-PGPUB; EPO; JPO	2003/11/25 13:58
27	142	((electro\$etch or electro\$etching or electro\$polish or electro\$polishing) and @ay<=2001) and cathode	US-PGPUB; EPO; JPO	2003/11/25 14:22
29	1	6251283.pn.	USPAT	2003/11/25 14:23
30	1	6251238.pn.	USPAT	2003/11/25 14:23
-	16979	cathode and (etch or etching or electro\$etch\$3 or electro\$polish\$3)	USPAT	2003/11/25 10:34
-	9350	(cathode and (etch or etching or electro\$etch\$3 or electro\$polish\$3)) and semiconductor	USPAT	2003/11/04 10:54
-	7335	((cathode and (etch or etching or electro\$etch\$3 or electro\$polish\$3)) and semiconductor) and (plate or mask)	USPAT	2003/11/04 10:55
-	5378	((cathode and (etch or etching or electro\$etch\$3 or electro\$polish\$3)) and semiconductor) and (plate or mask) and power	USPAT	2003/11/04 10:57
-	3614	((cathode and (etch or etching or electro\$etch\$3 or electro\$polish\$3)) and semiconductor) and (plate or mask) and power) and anode	USPAT	2003/11/04 10:57
-	1242	((cathode and (etch or etching or electro\$etch\$3 or electro\$polish\$3)) and semiconductor) and (plate or mask) and power) and anode) and (cathode same (etch or etching or electro\$etch))	USPAT	2003/11/04 11:04
-	438	((cathode and (etch or etching or electro\$etch\$3 or electro\$polish\$3)) and semiconductor) and (plate or mask) and power) and anode) and (cathode same (etch or etching or electro\$etch)) not plasma	USPAT	2003/11/04 11:18
-	432	((cathode and (etch or etching or electro\$etch\$3 or electro\$polish\$3)) and semiconductor) and (plate or mask) and power) and anode) and (cathode same (etch or etching or electro\$etch)) not plasma) and @ay<=2001	USPAT	2003/11/04 11:19
-	266	((cathode and (etch or etching or electro\$etch\$3 or electro\$polish\$3)) and semiconductor) and (plate or mask) and power) and anode) and (cathode same (etch or etching or electro\$etch)) not plasma) and @ay<=2001) and (solution or etchant or wet)	USPAT	2003/11/04 11:19
-	198	((cathode and (etch or etching or electro\$etch\$3 or electro\$polish\$3)) and semiconductor) and (plate or mask) and power) and anode) and (cathode same (etch or etching or electro\$etch)) not plasma) and @ay<=2001) and (solution or etchant or wet)) and mask	USPAT	2003/11/04 11:31

-	142	(((((cathode and (etch or etching or electro\$etch\$3 or electro\$ipolish\$3)) and semiconductor) and (plate or mask)) and power) and anode) and (cathode same (etch or etching or electro\$etch))) not plasma) and @ay<=2001) and (solution or etchant or wet)) and mask) not (emit or emitting)	USPAT	2003/11/04 11:32
-	47	("1166378"   "1393315"   "2689216"   "2923671"   "3300396"   "3317410"   "3558464"   "3652442"   "3808071"   "3809642"   "3953276"   "3962047"   "3986911"   "4032422"   "4118303"   "4233416"   "4304641"   "4323438"   "4466864"   "4469564"   "4596637"   "4664760"   "4906341"   "4931150"   "4966647"   "5000827"   "5023044"   "5152878"   "5222310"   "5228966"   "5284554"   "5308447"   "5318683"   "5377708"   "5391285"   "5421987"   "5429733"   "5431823"   "5435885"   "5437777"   "5443707"   "5447615"   "5486282"   "5543032"   "5807165"   "5865984"   "5911619").PN.	USPAT	2003/11/04 11:41
-	53	electro\$etch\$3 and semiconductor and cathode and anode	USPAT	2003/11/04 11:49